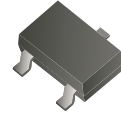


CMS3407-HF

P-Channel
RoHS Device
Halogen Free



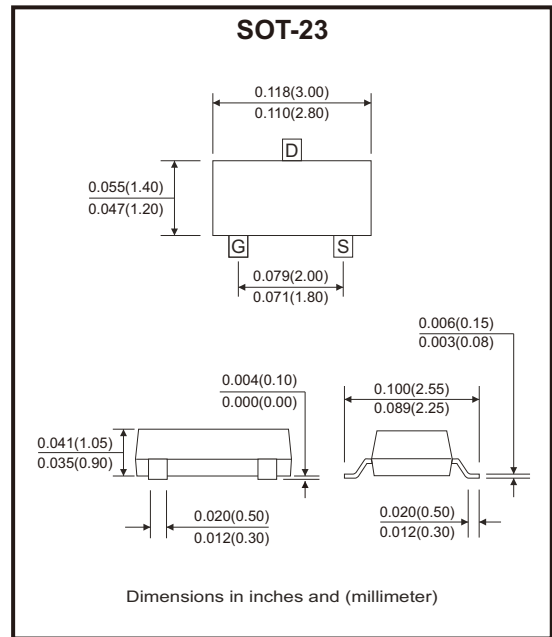
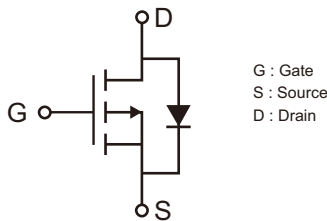
Features

- High power and current handling capability.
- Surface mount package.

Mechanical data

- Case: SOT-23, molded plastic.
- Mounting position: Any.

Circuit Diagram



Maximum Ratings (at Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V _{DS}	-30	V
Gate-source voltage	V _{GS}	±20	V
Drain current-continuous	I _D	-4.1	A
Drain current-pulsed (Note 1)	I _{DM}	-20	A
Power dissipation	P _D	1.4	W
Thermal resistance junction to ambient (Note 2)	R _{θJA}	90	°C/W
Operating junction and storage temperature range	T _J , T _{STG}	-55 to +150	°C

Notes: 1. Pulse width limited by maximum junction temperature.
 2. Surface mounted on FR4 board, t ≤ 10 sec.

Electrical Characteristics (at Ta=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	BV_{DSS}	$V_{GS} = 0V, I_D = -250\mu A$	-30	-33		V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -24V, V_{GS} = 0V$			-1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
On characteristics (Note 1)						
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1.1	-1.5	-2.1	V
Drain-source on-state resistance	$R_{DS(ON)}$	$V_{GS} = -10V, I_D = -4.1A$		48	65	m Ω
		$V_{GS} = -4.5V, I_D = -4A$		60	95	
Forward transconductance	g_{FS}	$V_{DS} = -5V, I_D = -1A$		10		S
Dynamic characteristics (Note 2)						
Input capacitance	C_{iss}	$V_{DS} = -15V, V_{GS} = 0V, f = 1MHz$		650		pF
Output capacitance	C_{oss}			105		
Reverse transfer capacitance	C_{rss}			65		
Switching characteristics (Note 2)						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -15V, R_L = 3.6\Omega$ $V_{GS} = -10V, R_{GEN} = 3\Omega$		8.5		ns
Turn-on rise time	t_r			4.5		
Turn-off delay time	$t_{d(off)}$			26		
Turn-off fall time	t_f			12.5		
Total gate charge	Q_g	$V_{DS} = -15V, I_D = -4A, V_{GS} = -10V$		12.5		nC
Gate-source charge	Q_{gs}			2.8		
Gate-drain charge	Q_{gd}			2.7		
Drain-source diode characteristics						
Diode forward voltage (Note 1)	V_{SD}	$V_{GS} = 0V, I_S = -4.1A$			-1.2	V

Notes: 1. Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.

2. Guaranteed by design, not subject to production.

Rating and Characteristic Curves (CMS3407-HF)

Fig.1 - Power Dissipation

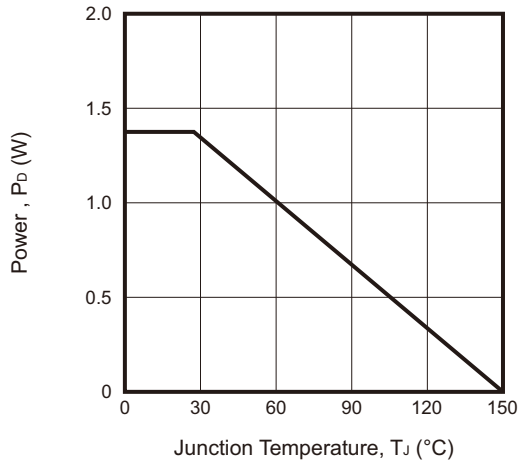


Fig.2 - Drain Current

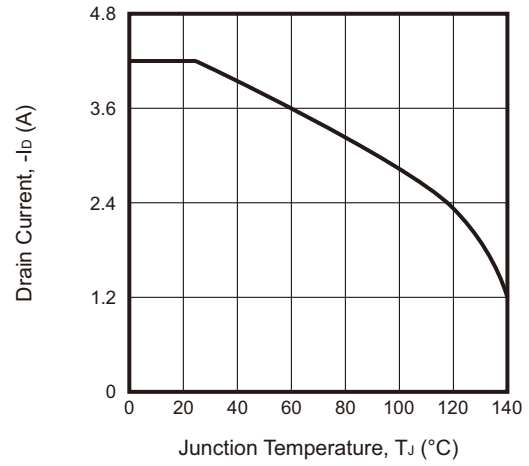


Fig.3 - Output Characteristics

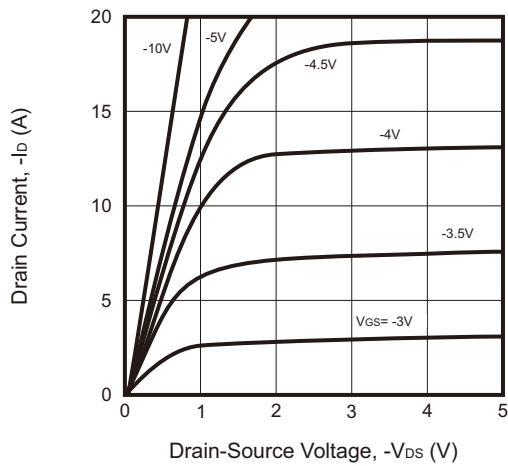


Fig.4 - Drain-Source on Resistance

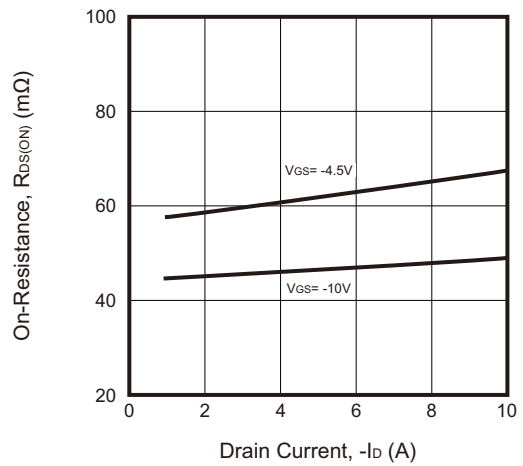


Fig.5 - Transfer Characteristics

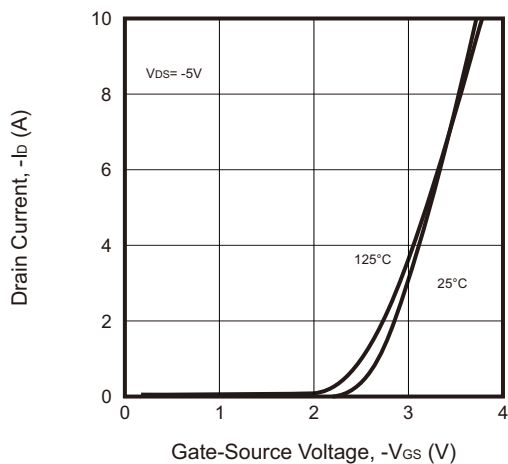
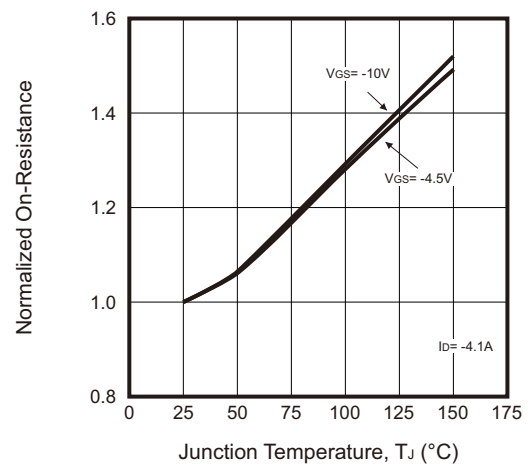


Fig.6 - Drain-Source on Resistance



Rating and Characteristic Curves (CMS3407-HF)

Fig.7 - $R_{DS(ON)}$ vs V_{GS}

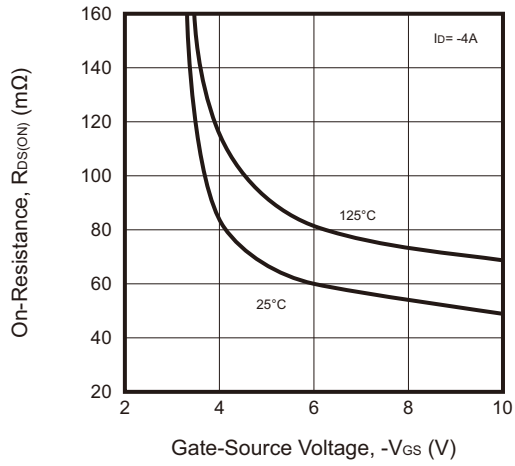


Fig.8 - Capacitance vs V_{DS}

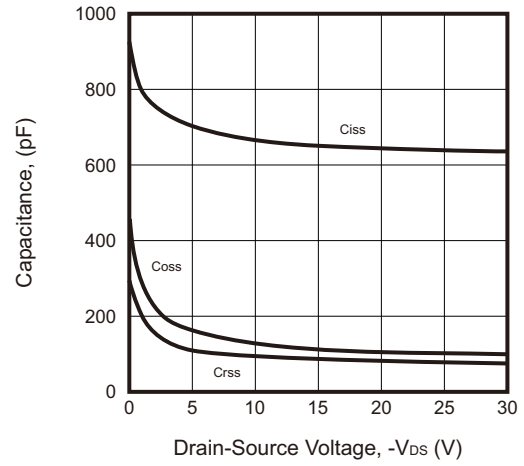


Fig.9 - Gate Charge

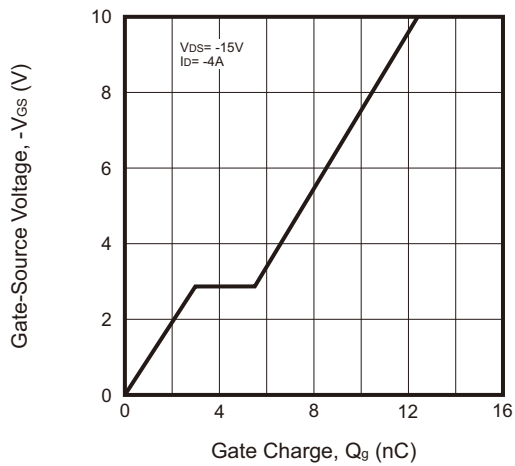


Fig.10 - Source-Drain Diode Forward

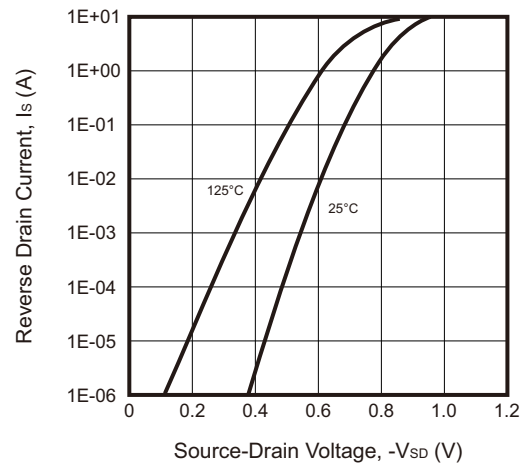
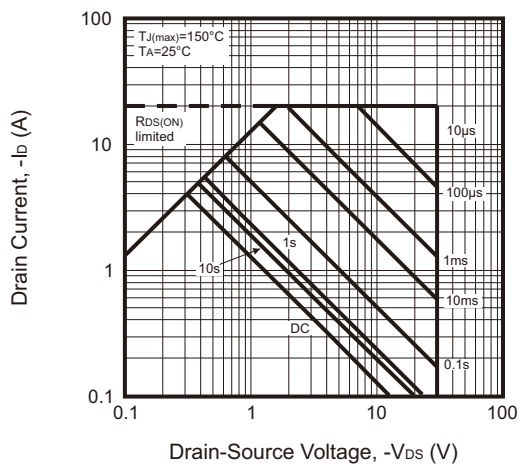
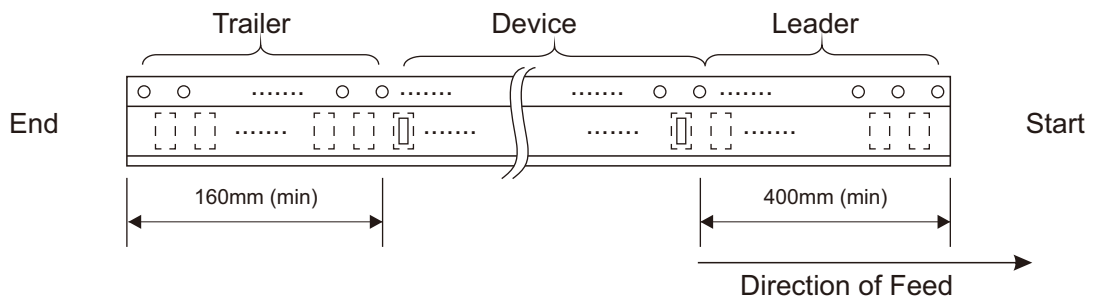
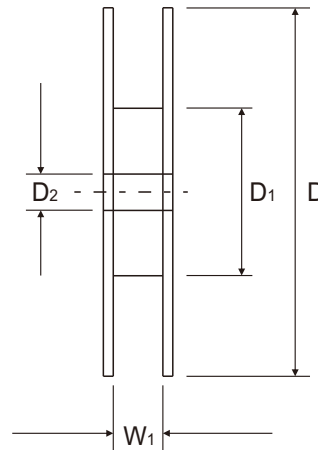
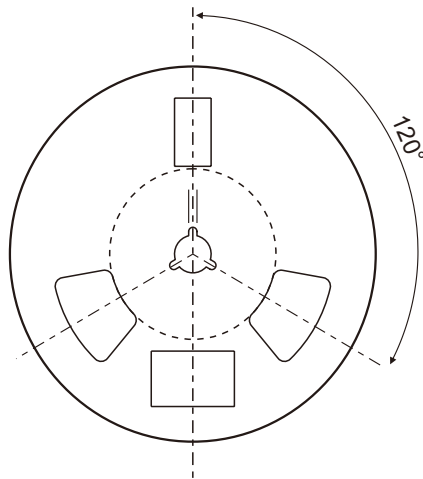
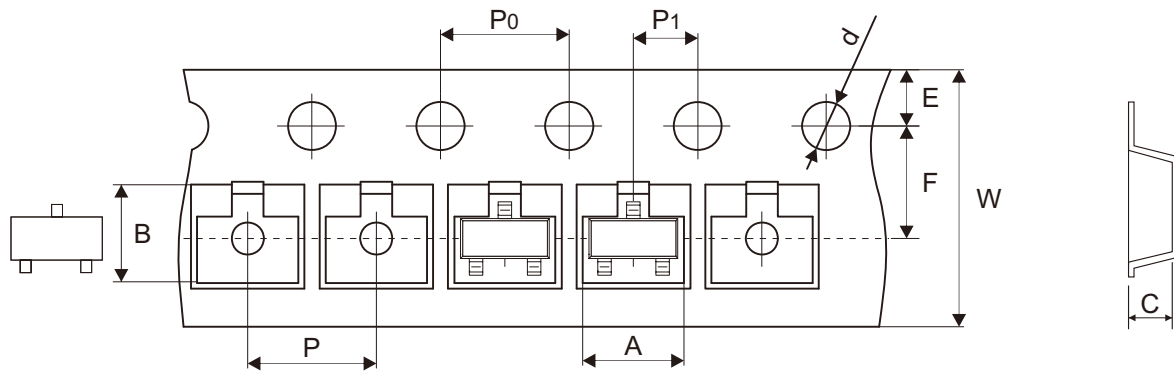


Fig.11 - Safe Operation Area



Reel Taping Specification

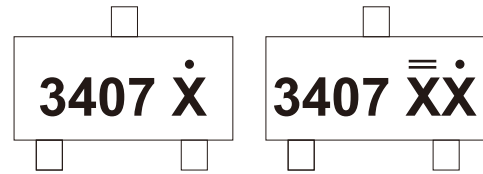


SOT-23	SYMBOL	A	B	C	d	D	D ₁	D ₂
	(mm)	3.15 ± 0.10	2.77 ± 0.10	1.22 ± 0.10	1.50 + 0.10 - 0.00	178.00 ± 2.00	50.00 ± 0.50	13.00 ± 0.25
	(inch)	0.124 ± 0.004	0.109 ± 0.004	0.048 ± 0.004	0.059 + 0.004 - 0.000	7.008 ± 0.079	1.969 ± 0.020	0.512 ± 0.010

SOT-23	SYMBOL	E	F	P	P ₀	P ₁	W	W ₁
	(mm)	1.75 ± 0.10	3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	8.00 + 0.30 - 0.10	9.50 ± 1.50
	(inch)	0.069 ± 0.004	0.138 ± 0.002	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	0.315 + 0.012 - 0.004	0.374 ± 0.059

Marking Code

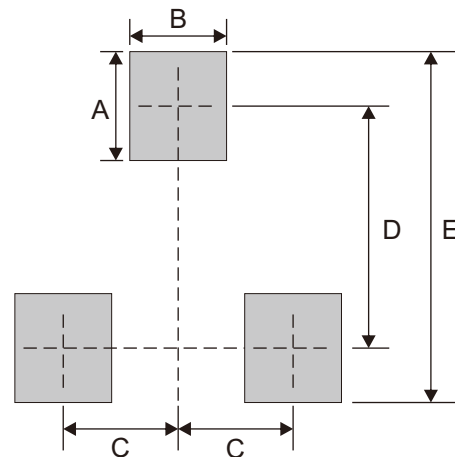
Part Number	Marking Code
CMS3407-HF	3407



$\dot{X} / \bar{\bar{X}}\dot{X}$ = Control code

Suggested P.C.B. PAD Layout

SIZE	SOT-23	
	(mm)	(inch)
A	0.90	0.035
B	0.80	0.031
C	0.95	0.037
D	2.00	0.079
E	2.90	0.114



Note: 1. The pad layout is for reference purposes only.

Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOT-23	3,000	7